FORM PTO-1449 (REV. 7-80) U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DOCKET NO.	SERIAL NO.
LIST OF DOCUMENTS CITED BY APPLICANT *(Use several sheets if necessary)*	**TI-33227.1**	**TBD**
	APPLICANT: **Xiaoju Wu**	
	FILING DATE **Herewith**	GROUP **TBD**

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
		5,406,110	**04/11/95**	**Kwon et al.**	**257**	**493**	**02/01/1994**

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		DOCUMENT NUMBER	DATE	COUNTRY		CLASS	SUBCLASS	TRANSLATION	
								YES	NO

OTHER DOCUMENTS *(Including Author, Title, Date, Pertinent Pages, Etc.)*

		"Implementation of High Side High Voltage RESURF LDMOS in a Sub-half Micron Smart Power Technology", Zhu et al, Proceedings of 2001 International Symposium on Power Semiconductor Devices & ICs, June, 2001, pp 403-406
		"16-60V Rated LDMOS Show Advanced Performance in an 0.72μ Evolution BiCMOS Power Technology", Tsai et al, IEEE, 1997, pp 367-370

EXAMINER	DATE CONSIDERED

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.